# Journal of Zhejiang University-SCIENCE A

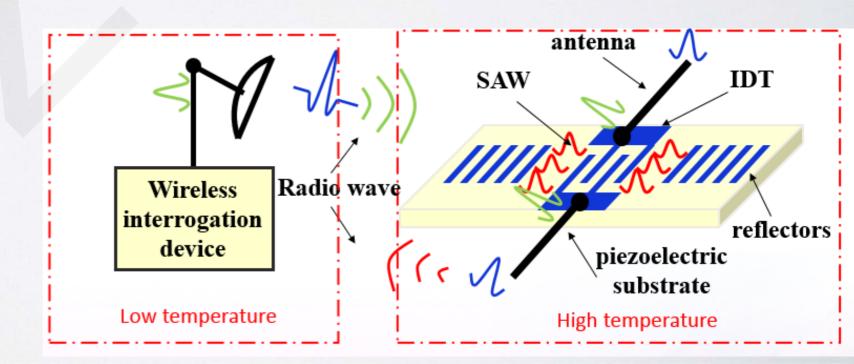
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# Design and fabrication of an surface acoustic wave resonator based on AIN/4H-SiC material for harsh environments

# Key words:

SAW resonator, AIN/4H-SiC, harsh environment, MEMS technology, gas turbine



## application requirement



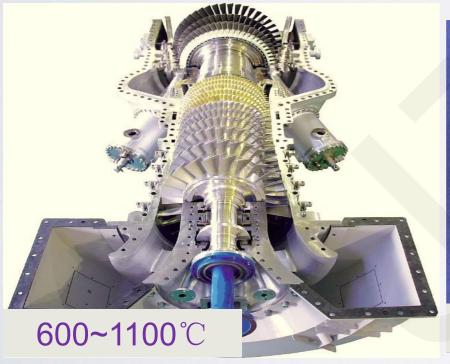
terrestrial heat exploitation



automotive engines



hypersonic aircraft



gas turbine



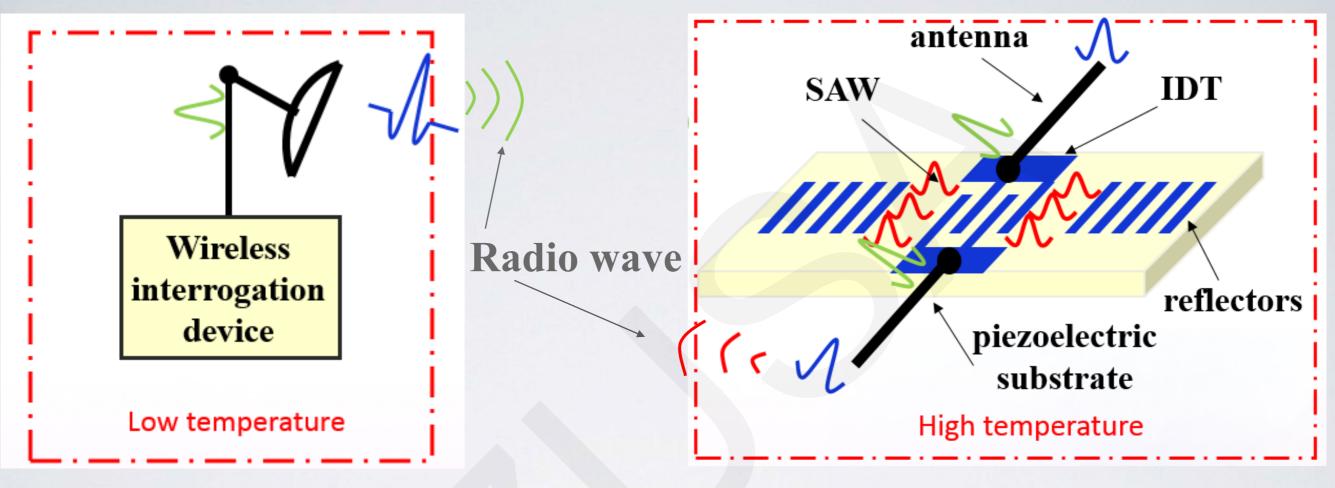
300~1000℃



turbojet engine

near space aerocraft

photos source: google search

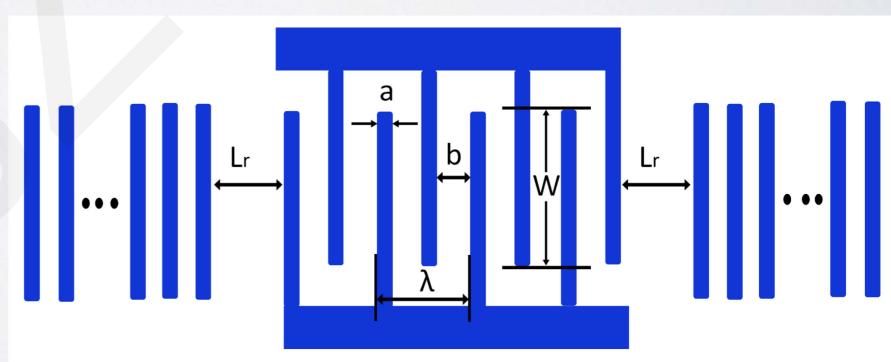


High-temperature Wireless MEMS Temperature Sensing System

### Parameter design

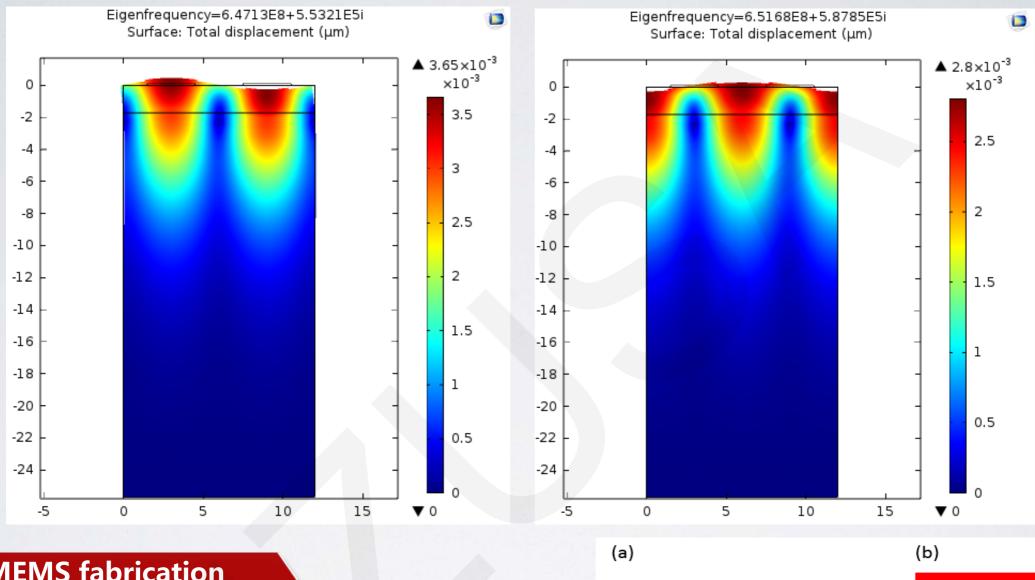
$$f = \frac{V_s}{\lambda_0} \quad a + b = N \frac{\lambda_0}{2}$$

$$L_r = (N - \frac{1}{2}) \frac{\lambda_0}{2}$$



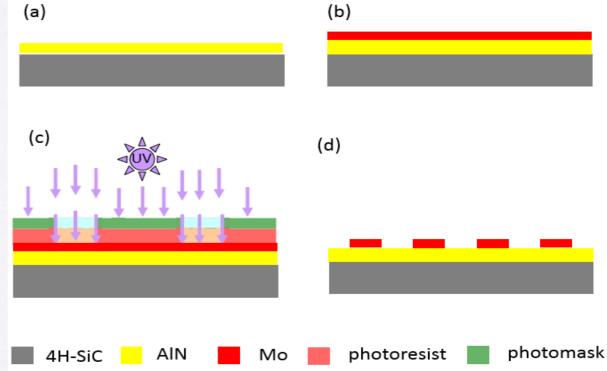
#### **FEM simulation**

Finite element simulation software COMSOL Multiphysics is used to simulate the device performance



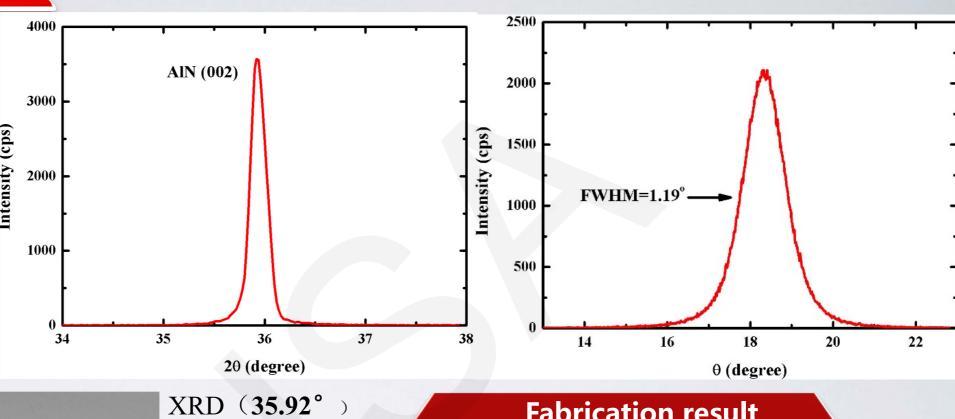
#### **MEMS fabrication**

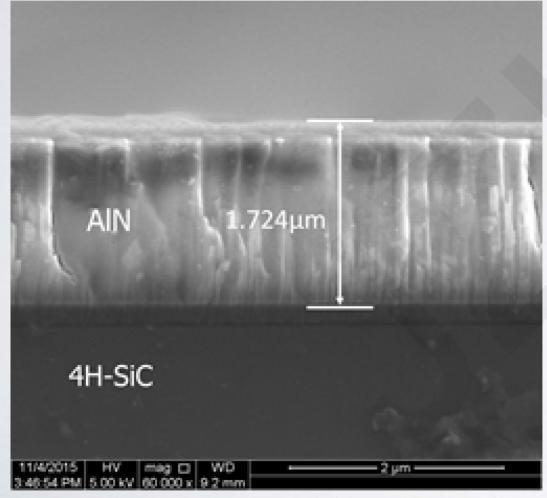
- (a) AlN is deposited as piezoelectric layer on 4H-SiC.
- (b) Mo is deposited on AlN.
- (c) Mo is patterned through photoetching.
- (d) IDT and reflecting grating electrode were fabricated by wet etching.



## c-axis-oriented AIN thin films

- ➤ AlN thin film exhibits columnar grains perpendicular to the surface of the 4H–SiC layer
- High quality c-axis-oriented AlN thin film was grown on the 4H–SiC layer





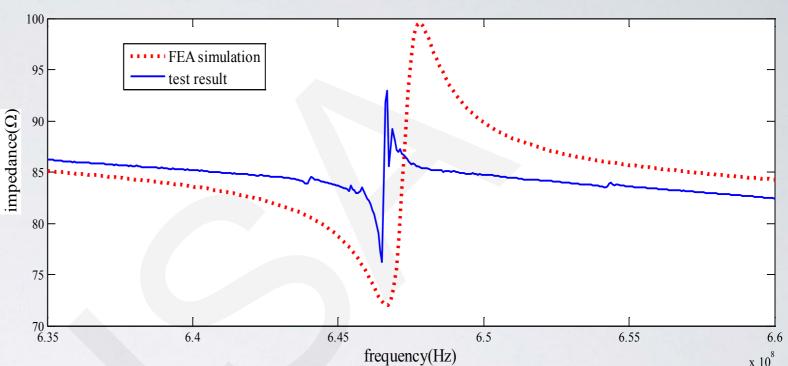


Cross-sectional SEM micrographs of the 4H-SiC and AlN films

Optical image of the fabricated resonator

#### resonance frequency test





frequency-impedance chart of the FEA simulation and test result.

#### conclusions

- For the first time, a SAW resonator (size: 1107μm×721μm) based on the AlN/4H-SiC multi-layer structure is designed and fabricated in this work.
- ➤ Highly c-axis-oriented AlN thin films were success-fully deposited on the 4H–SiC substrate by using RF reactive magnetron sputtering and the lowest FWHM value is only 1.19°.
- > a MEMS-compatible fabrication process has been employed to fabricate the SAW resonator.
- In comparison with the simulation curve, the test results of the network analyzer are consistent with it.